Electronic Acknowledgement Receipt FES ID: 1074105 Application Number: 10812015 Confirmation Number: 2799 Gallium nitride (GaN)-based semiconductor light emitting diode and Title of Invention: method for manufacturing the same First Named Inventor: Seung Wan Chae LOWE HAUPTMAN GILMAN & BERNER, LLP Suite 310 Correspondence Address: 1700 Diagonal Road Alexandria VA 22314 US 7036841111 Filer: Benjamin J. Hauptman/Ayesha Wilson Filer Authorized By: Benjamin J. Hauptman Attorney Docket Number: 2336-255 Receipt Date: 09-JUN-2006 Filing Date: 30-MAR-2004 Time Stamp: 17:25:53 Application Type: Utility International Application Number: Payment information:

no

Submitted with Payment

File Listing:

Number	Document Description	File Name	File Size(Bytes)	Part	Pages
1	Amendment - After Non-Final Rejection	20060609Amendment.pdf	327891	no	8
Warnings:					
Information					

This Acknowledgement Receipt evidences receipt on the noted date by the USPTO of the indicated documents, characterized by the applicant, and including page counts, where applicable. It serves as evidence of receipt similar to a Post Card. as described in MPEP 503.

Total Files Size (in bytes):

327891

New Applications Under 35 U.S.C. 111

If a new application is being filed and the application includes the necessary components for a filing date (see 37 CFR 1.53(b)-(d) and MPEP 506), a Filing Receipt (37 CFR 1.54) will be issued in due course and the date shown on this Acknowledgement Receipt will establish the filing date of the application.

National Stage of an International Application under 35 U.S.C. 371

If a timely submission to enter the national stage of an international application is compliant with the conditions of 35 U.S.C. 371 and other applicable requirements a Form PCT/DO/EO/903 indicating acceptance of the application as a national stage submission under 35 U.S.C. 371 will be issued in addition to the Filing Receipt, in due course.